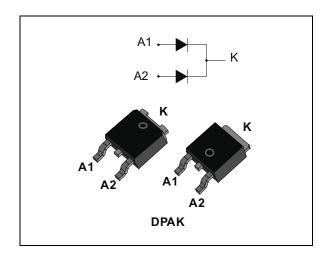


STPS15L60C

Power Schottky rectifier

Datasheet - production data

www.st.com



Features

Very small conduction losses

This is information on a product in full production.

- · Negligible switching losses
- Low forward voltage drop
- Avalanche specification
- ECOPACK[®]2 compliant component for DPAK on demand

Description

Dual center tab Schottky rectifier suited for switched mode power supply and high frequency DC to DC converters.

Packaged in DPAK, this device is intended for use in low voltage, high frequency inverters, freewheeling and polarity protection applications.

Table 1. Device summary

Symbol	Value
I _{F(AV)}	2 x 7.5 A
V_{RRM}	60 V
T _{j(max)}	150 °C
V _F (typ)	0.52 V

Characteristics STPS15L60C

1 Characteristics

Table 2. Absolute ratings (limiting values per diode at 25 °C unless otherwise stated)

Symbol	Parameter	Value	Unit			
V_{RRM}	Repetitive peak reverse voltage	Repetitive peak reverse voltage				
I _{F(RMS)}	Forward rms current	10				
1	Average forward current, $\delta = 0.5$, square	$T_{a} = 135 {}^{\circ}\text{C}^{(1)}$	Per diode	7.5	Α	
I _{F(AV)} wave	wave		Per device	15		
I _{FSM}	Surge non repetitive forward current $t_p = 10 \text{ ms sinusoidal}$			75	Α	
P _{ARM}	Repetitive peak avalanche power	265	W			
T _{stg}	Storage temperature range	-65 to +175	°C			
Tj	Maximum operating junction temperature ⁽²⁾			150	°C	

^{1.} Value based on $R_{th(j-c)}$ max (per diode)

Table 3. Thermal resistances

Symbol	Parameter	Value	Unit	
D	Junction to case	Per diode	4	
R _{th(j-c)}		Total	2.4	°C/W
R _{th(c)}	Coupling		0.7	

When the diodes 1 and 2 are used simultaneously:

 $\Delta T_{j}(diode 1) = P(diode 1) \times R_{th(j-c)}(Per diode) + P(diode 2) \times R_{th(c)}$

Table 4. Static electrical characteristics (per diode)

Symbol	Parameter	Test Conditions		Min.	Тур.	Max.	Unit
I _R ⁽¹⁾ Reverse leakage current	Povorso loakago current	T _j = 25 °C	\/ - \/			200	μΑ
'R`'	I _R ⁽¹⁾ Reverse leakage current	T _j = 125 °C	$V_R = V_{RRM}$		45	60	mA
	V _F ⁽¹⁾ Forward voltage drop	T _j = 25 °C	I _F = 7.5 A			0.62	
		T _j = 125 °C			0.52	0.57	•
v (1)		T _j = 25 °C	I _F = 12 A			0.76	V
VF'		T _j = 125 °C			0.62	0.68	V
		T _j = 25 °C	I _F = 15 A			0.82	
		T _j = 125 °C			0.66	0.72	

^{1.} Pulse test: t_p = 380 μ s, δ < 2%

To evaluate the conduction losses use the following equation:

$$P = 0.32 \text{ x } I_{F(AV)} + 0.027 I_{F}^{2}_{(RMS)}$$

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^{2.} $\frac{dPtot}{dTj} < \frac{1}{Rth(j-a)}$ condition to avoid thermal runaway for a diode on its own heatsink

STPS15L60C Characteristics

versus average forward current (per diode)

P_{F(AV)}(W)

5.5

5.0

4.5

4.0

3.5

3.0

2.5

2.0

1.5

1.0

δ= tp/T

Figure 1. Average forward power dissipation

Figure 2. Average forward current versus ambient temperature (δ = 0.5)(per diode) $I_{\mathsf{F}(\mathsf{AV})}(\mathsf{A})$ 9 R_{th(j-a)}= R_{th(j-c)} 8 7 6 5 R_{th(j-a)}= 70 °C/W 4 3 2 1 T_{amb}(°C) 0 75 0 25 50 100 125 150

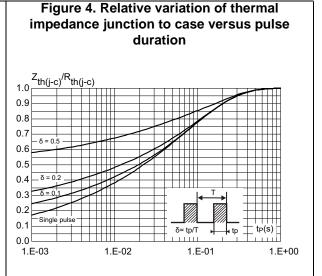
Figure 3. Normalized avalanche power derating versus pulse duration at T_j = 125 °C

PARM(tp)
PARM(10 µs)

0.01

0.01

1 10 100 1000



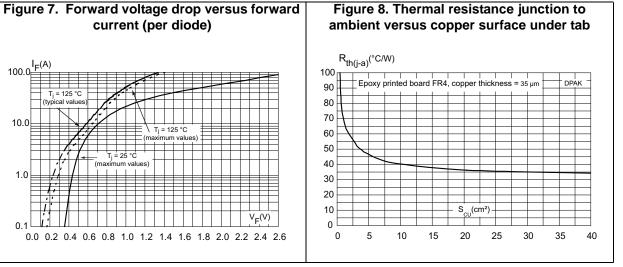
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Figure 5. Reverse leakage current versus reverse voltage applied (typical values, per diode) I_R(mA) 1.E+03 Tj = 150 °C-1.E+02 1.E+01 1.E+00 15 20 25 30 35 40 45 50 55 60 10

Figure 6. Junction capacitance versus reverse voltage applied (typical values, per diode) 1000 C(pF) 100 100

current (per diode) 100.0 I_F(A) 10.0

0.0 0.2 0.4 0.6 0.8 1.0 1.2 1.4 1.6 1.8 2.0 2.2 2.4 2.6



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STPS15L60C **Package Information**

2 **Package Information**

- Epoxy meets UL94,V0
- Cooling method: by conduction (C)

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: www.st.com. ECOPACK[®] is an ST trademark.

2.1 **DPAK** package information

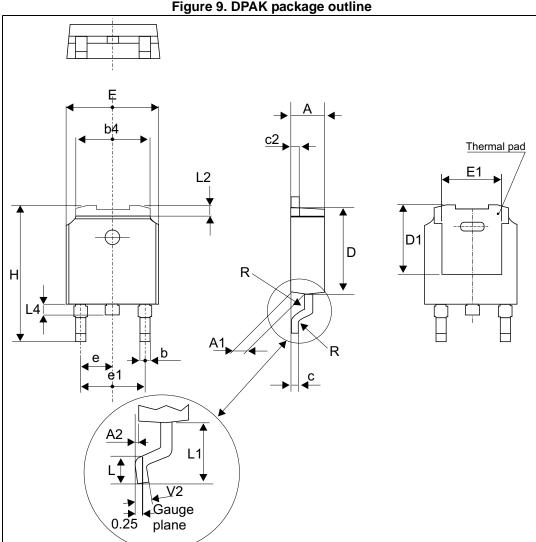


Figure 9. DPAK package outline

Note:

This package drawing may slightly differ from the physical package. However, all the specified dimensions are guaranteed.



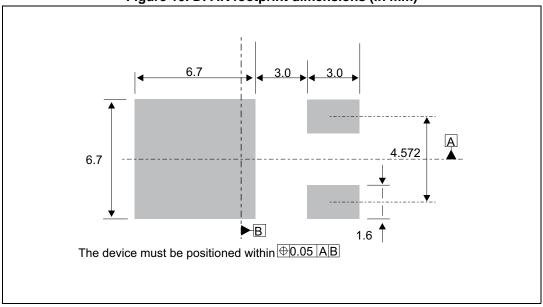
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Package Information STPS15L60C

Table 5. DPAK package mechanical data

	Dimensions						
Ref.	Ref.		Millimeters		Inches		
	Min.	Тур.	Max.	Min.	Тур.	Max.	
Α	2.18		2.40	0.085		0.094	
A1	0.90		1.10	0.035		0.043	
A2	0.03		0.23	0.001		0.009	
b	0.64		0.90	0.025		0.035	
b4	4.95		5.46	0.194		0.214	
С	0.46		0.61	0.018		0.024	
c2	0.46		0.60	0.018		0.023	
D	5.97		6.22	0.235		0.244	
D1	4.95		5.60	0.194		0.220	
Е	6.35		6.73	0.250		0.264	
E1	4.32		5.50	0.170		0.216	
е		2.28			0.090		
e1	4.40		4.70	0.173		0.185	
Н	9.35		10.40	0.368		0.409	
L	1.00		1.78	0.039		0.070	
L2			1.27			0.050	
L4	0.60		1.02	0.023		0.040	
V2	-8°		+8°	-8°		8°	

Figure 10. DPAK footprint dimensions (in mm)



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3 Ordering Information

Table 6. Ordering information

Order code	Marking	Package	Weight	Base qty	Delivery mode
STPS15L60CB	S15L60C	DPAK	0.32 g	75	Tube
STPS15L60CB-TR	S15L60C	DPAK	0.32 g	2500	Tape and reel

4 Revision history

Table 7. Document revision history

Date	Revision Description of Changes	
27-Jun-2012	2	Automatic revalidation date workflow started.
07-Jan-2015 3 Updated DPAK package information and reformation current standard.		Updated DPAK package information and reformatted to current standard.
18-Dec-2015	4	Updated DPAK package information and reformatted to current standard.



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